

Single bilateral switch

Features

■ High speed:

$$t_{PD} = 0.3 \text{ ns (typ.)}$$
 at $V_{CC} = 5 \text{ V}$
 $t_{PD} = 0.4 \text{ ns (typ.)}$ at $V_{CC} = 3.3 \text{ V}$

■ Low power dissipation:

$$I_{CC} = 1 \mu A \text{ (max.)}$$
 at $T_A = 25 \text{ °C}$

■ Low "ON" resistance:

$$R_{ON}$$
 = 6.5 Ω (typ.) at V_{CC} = 5 $\,$ V $I_{I/O}$ = 1 mA R_{ON} = 8.5 Ω (typ.) at V_{CC} = 3.3 V $I_{I/O}$ = 1 mA

■ Sine wave distortion: 0.04% at V_{CC} = 3.3 V f = 1 kHz

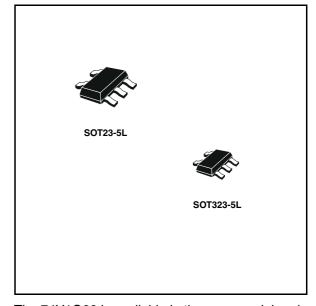
■ Wide operating range: V_{CC} (opr) = 2 V to 5.5 V

■ Improved latch-up immunity

Description

The 74V1G66 is an advanced high-speed CMOS single bilateral switch fabricated in silicon gate $\mbox{$\rm C^2$MOS}$ technology. It achieves high speed propagation delay and very low ON resistances while maintaining true CMOS low power consumption. This bilateral switch handles rail to rail analog and digital signals that may vary across the full power supply range (from GND to $\mbox{$\rm V_{CC}$}).$

The C input is provided to control the switch and it is compatible with standard CMOS outputs. The switch is ON (port I/O is connected to port O/I) when the C input is held high and OFF (high impedance state exists between the two ports) when C is held low. It can be used in many applications as battery powered systems or test equipments.



The 74V1G66 is available in the commercial and extended temperature range in SOT23-5L and SOT323-5L packages.

All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Table 1. Device summary

Order code	Package	Packaging
74V1G66STR	SOT23-5L	Tape and reel
74V1G66CTR	SOT323-5L	Tape and reel

Pin connection 74V1G66

1 Pin connection

Figure 1. Pin connection and IEC logic symbols

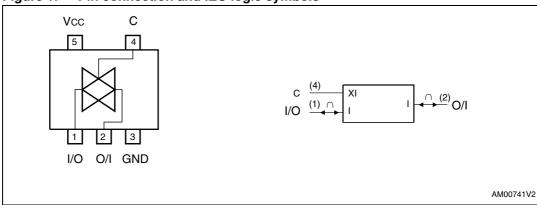


Table 2. Pin description

Pin number	Symbol	Name and function
1	I/O	Independent input/output
2	O/I	Independent output/input
3	GND	Ground (0 V)
4	С	Enable input (active high)
5	V _{CC}	Positive supply voltage

Figure 2. Input equivalent circuit

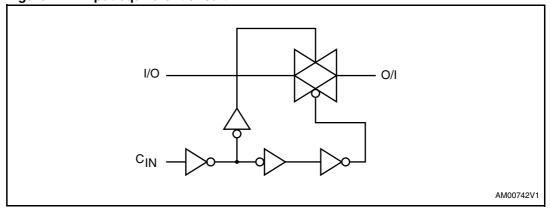


Table 3. Truth table

Control	Switch function
Н	ON
L	OFF ⁽¹⁾

^{1.} High impedance state.

74V1G66 Maximum rating

2 Maximum rating

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to +7.0	V
VI	DC input voltage	-0.5 to V _{CC} + 0.5	V
V _{IC}	DC control input voltage	-0.5 to +7.0	V
Vo	DC Output voltage	-0.5 to V _{CC} + 0.5	V
I _{IK}	DC input diode current	±20	mA
I _{IK}	DC control input diode current	- 20	mA
I _{OK}	DC output diode current	±20	mA
Io	DC output current	±50	mA
I _{CC} or I _{GND}	DC V _{CC} or ground current	±50	mA
T _{stg}	Storage temperature	-65 to +150	°C
T _L	Lead temperature (10 sec)	300	°C

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	2 to 5.5	V
VI	Input voltage	0 to V _{CC}	V
V _{IC}	Control input voltage	0 to 5.5	٧
V _O	Output voltage	0 to V _{CC}	٧
T _{op}	Operating temperature	-55 to 125	°C
dt/dv	Input rise and fall time ⁽¹⁾ $V_{CC} = 5.0 \text{ V}$	0 to 20	ns/V

^{1.} V_{IN} from 30% to 70% of V_{CC} on control pin.

Maximum rating 74V1G66

Table 6. DC specifications

		Tes	st condition	Value							
Symbol	Parameter	V _{CC}		T _A = 25°C			-40 to	85°C	-55 to 125°C		Unit
		(V)		Min	Тур	Max	Min	Max	Min	Max	
	High level input	2.0		1.5			1.5		1.5		
V _{IH}	voltage	2.7 to 5.5		0.7V _C			0.7V CC		0.7V CC		V
	Low level input	2.0				0.5		0.5		0.5	
V _{IL}	voltage	2.7 to 5.5				0.3V _C		0.3V CC		0.3V CC	V
		3.3 ⁽¹⁾	$V_{IC} = V_{IH}$		12.5	21		23		27	
R _{ON}	ON resistance 5.0 ⁽²⁾	5.0 ⁽²⁾	$V_{I/O} = V_{CC}$ to GND $I_{I/O} \le 1 \text{ mA}$		7.5	10		12		14	Ω
		3.3 ⁽¹⁾	$V_{IC} = V_{IH}$		8.5	11.5		12.5		15	Ω
R _{ON}	ON resistance	5.0 ⁽²⁾	$V_{I/O} = V_{CC}$ or GND $I_{I/O} \le 1$ mA		6.5	8.5		10		12	
l _{OFF}	Input/output leakage current (switch OFF)	5.5	$V_{OS} = V_{CC} \text{ to}$ GND $V_{IS} = V_{CC} \text{ to}$ GND $V_{IC} = V_{IL}$			±0.1		±1		±5	μА
I _{IZ}	Switch input leakage current (switch ON, output open)	5.5	$V_{OS} = V_{CC}$ to GND $V_{IC} = V_{IH}$			±0.1		±1		±5	μА
I _{IN}	Control input leakage current	0 to 5.5	V _{IC} = 5.5V or GND			±0.1		±1.0		±1.0	μА
I _{CC}	Quiescent supply current	5.5	V _I = V _{CC} or GND			1		10		20	μА

^{1.} Voltage range is $3.3 \text{ V} \pm 0.3 \text{ V}$.

^{2.} Voltage range is 5 V \pm 0.5 V.

74V1G66 Maximum rating

Table 7. AC electrical characteristics ($C_L = 50 \text{ pF}$, input $t_r = t_f = 3 \text{ ns}$)

		Test condition		Value							
Symbol Paramete	Parameter	V _{CC}		T _A = 25°C			-40 to 85°C		-55 to 125°C		Unit
		(V)		Min	Тур	Max	Min	Max	Min	Max	
	Delay time	3.3 ⁽¹⁾	$t_r = t_f = 6 \text{ ns}$		0.4	0.8		1.2		2.4	20
t _{PD}	Delay liftle	5.0 ⁽²⁾			0.3	0.6		1.0		2.0	ns
t _{PLZ}	Output disable	3.3 ⁽¹⁾	$R_1 = 500 \Omega$		5.0	7.5		9.0		10.0	ns
t _{PHZ}	time	5.0 ⁽²⁾	HL = 300 t2		5.0	7.5		9.0		10.0	115
t _{PZL}	PZL Quitaut anabla tima	3.3 ⁽¹⁾	D 11/0		2.5	4.0		5.0		7.0	no
t _{PZH} Output enable time	5.0 ⁽²⁾	$R_L = 1 K\Omega$		2.0	4.0		5.0		7.0	ns	

^{1.} Voltage range is 3.3 V \pm 0.3 V.

Table 8. Capacitive characteristics

		1	Test condition		Value						
Symbol Parameter	V _{CC}		T _A = 25°C			-40 to 85°C		-55 to 125°C		Unit	
	(V)	Min	Тур	Max	Min	Max	Min	Max			
C _{IN}	Input capacitance				3	10		10		10	pF
C _{I/O}	Output capacitance				10						pF
	Power dissipation 3.3	3.3			2.5						pF
C _{PD} capacitance ⁽¹⁾	5.0			3						рг	

C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to the test circuit). Average operating current can be obtained by the following equation. I_{CC}(opr) = C_{PD} x V_{CC} x f_{IN} + I_{CC}.

^{2.} Voltage range is 5 V \pm 0.5 V.

Maximum rating 74V1G66

Table 9. Analog switch characteristics (GND = 0 V; $T_A = 25$ °C)

			Test condition				
Symbol	Parameter	V _{CC} (V)	V _{IN} (V _p -		Тур	Unit	
	Sine wave	3.3 ⁽¹⁾	2.75	f 1 KU- D 10 KO C 50 pF		%	
	distortion (THD)	5.0 ⁽²⁾	4	$f_{IN} = 1 \text{ KHz R}_L = 10 \text{ K}\Omega \text{ C}_L = 50 \text{ pF}$	0.04	/0	
				Adjust f _{IN} voltage to obtain 0 dBm at V _{OS} .			
f _{MAX}	response (switch ON)	5.0 ⁽²⁾	Increase f_{IN} Frequency until dB meter reads -3dB R_L = 50 Ω C_L = 10 pF			MHz	
	Feed through	3.3 ⁽¹⁾		centered at V _{CC} /2	-60	j	
	attenuation (switch OFF)	5.0 ⁽²⁾		f_{IN} Voltage to obtained 0dBm at V_{IS} 600 Ω C_L = 50 pF, f_{IN} = 1KHz sine wave	-60	dB	
	Crosstalk	3.3 ⁽¹⁾	B ₁ = 6	600Ω , C _I = 50 pF, f _{IN} = 1 KHz square wave			
(control input to signal output)		5.0 ⁽²⁾	$t_r = t_f = 6 \text{ ns}$		60	mV	

^{1.} Voltage range is 3.3 V \pm 0.3 V

^{2.} Voltage range is 5.0 V ± 0.5 V

Switching characteristics test circuit 3

Figure 3. Enable and disable timing (circuit) Figure 4. **Enable and disable timing** (waveform)

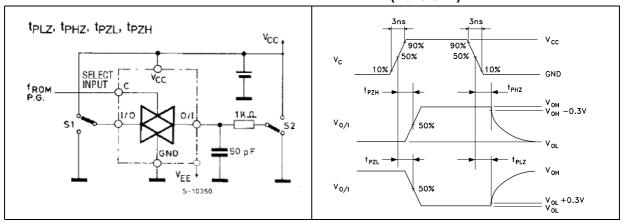


Figure 5. Resistive feedthrough attenuation Figure 6. Capacitive feedthrough attenuation

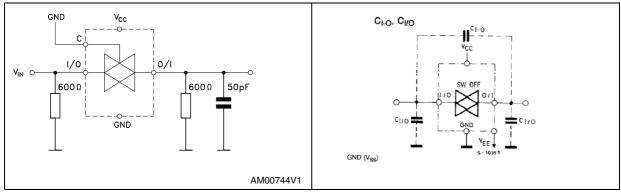


Figure 7. **Bandwidth attenuation**

Figure 8. **Maximum control frequency** 50Ω 50Ω 10pF GND SC15040

Figure 9. Crosstalk (control to output)

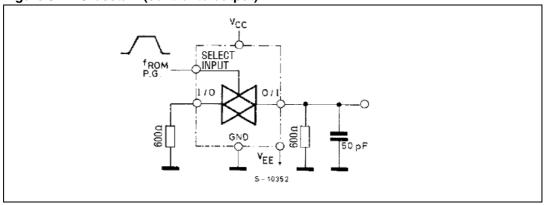


Figure 10. Channel resistance (R_{ON})

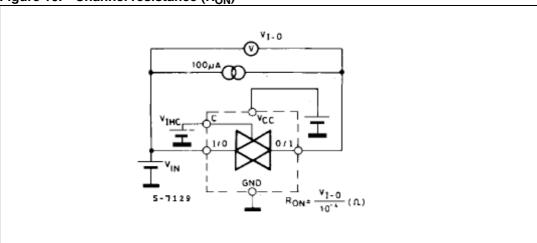
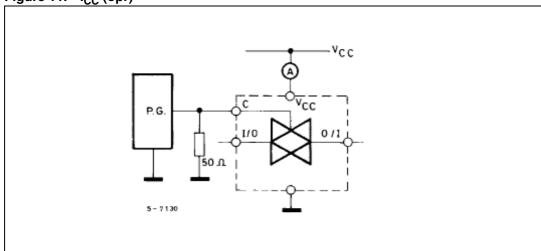


Figure 11. I_{CC} (opr)



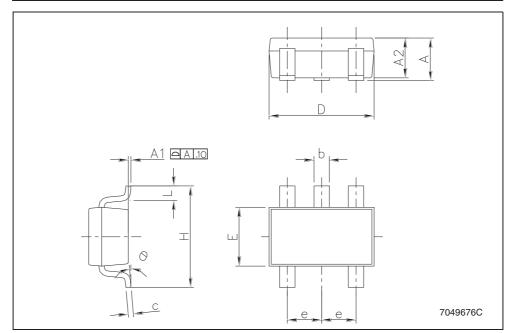
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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SOT23-5L MECHANICAL DATA

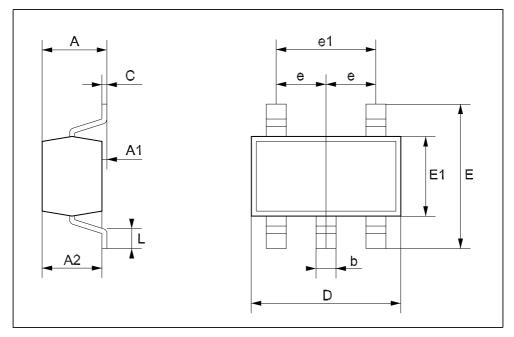
DIM		mm.		mils			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	0.90		1.45	35.4		57.1	
A1	0.00		0.10	0.0		3.9	
A2	0.90		1.30	35.4		51.2	
b	0.35		0.50	13.7		19.7	
С	0.09		0.20	3.5		7.8	
D	2.80		3.00	110.2		118.1	
E	1.50		1.75	59.0		68.8	
е		0.95			37.4		
Н	2.60		3.00	102.3		118.1	
L	0.10		0.60	3.9		23.6	



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SOT323-5L MECHANICAL DATA

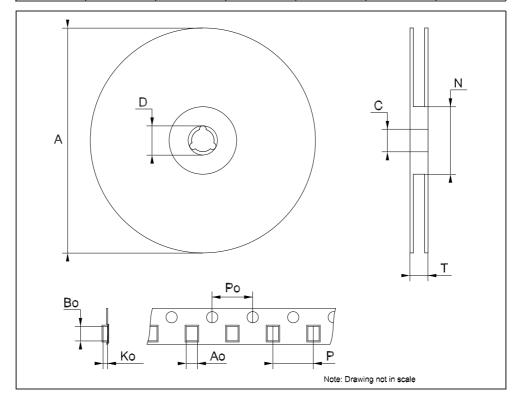
DIM.		mm.		mils			
DIW.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	0.80		1.10	31.5		43.3	
A1	0.00		0.10	0.0		3.9	
A2	0.80		1.00	31.5		39.4	
b	0.15		0.30	5.9		11.8	
С	0.10		0.18	3.9		7.1	
D	1.80		2.20	70.9		86.6	
E	1.80		2.40	70.9		94.5	
E1	1.15		1.35	45.3		53.1	
е		0 .65			25.6		
e1		1.3			51.2		
L	0.10		0.30	3.9		11.8	



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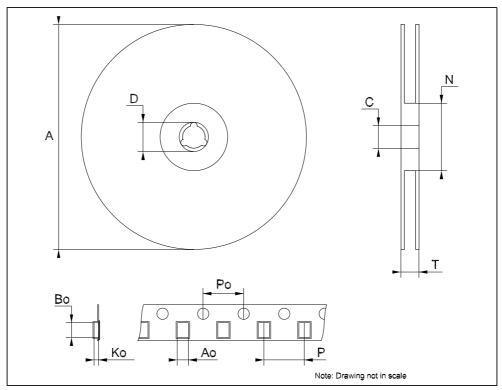
Tape & Reel SOT23-xL MECHANICAL DATA

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
А			180			7.086		
С	12.8	13.0	13.2	0.504	0.512	0.519		
D	20.2			0.795				
N	60			2.362				
Т			14.4			0.567		
Ao	3.13	3.23	3.33	0.123	0.127	0.131		
Во	3.07	3.17	3.27	0.120	0.124	0.128		
Ko	1.27	1.37	1.47	0.050	0.054	0.058		
Po	3.9	4.0	4.1	0.153	0.157	0.161		
Р	3.9	4.0	4.1	0.153	0.157	0.161		



Tape & Reel SOT323-xL MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А	175	180	185	6.889	7.086	7.283
С	12.8	13	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	59.5	60	60.5		2.362	
Т			14.4			0.567
Ao		2.25			0.088	
Во		2.7			0.106	
Ko		1.2			0.047	
Po	3.9	4	4.1	0.153	0.157	0.161
Р	3.8	4	4.2	0.149	0.157	0.165



Revision history 74V1G66

5 Revision history

Table 10. Document revision history

Date	Revision	Changes
01-Apr-2004	7	Updated data reel information.
28-Oct-2008 8		Document reformatted to improve readability. Updated <i>Table 6: DC specifications on page 4.</i>

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